Metamaterial Impedance Matching Network for Ambient RF-Energy Harvesting Operating at 2.4 GHz and 5 GHz

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Abstract: This paper points out the viability of the utilization of metamaterial transmission lines as a multifrequency impedance matching network, improving RF-Energy Harvesting systems operating around 2.4 GHz and 5 GHz. Metamaterial transmission lines introduce additional degrees of freedom in the transmission line design, providing the possibility to match the impedance in multiple bands. The impedance matching structure has been designed and optimized using ADS simulator to match the input impedance of a four-diode-bridge rectifier connected to an energy management system. The proposed Metamaterial Impedance Matching Network (MIMN) has been fabricated using standard PCB technologies and tested in a full operative ambient RF-Energy Harvesting System obtaining a DC output voltage of 1.8 V in a 6.8 mF supercapacitor.

Keywords: energy management system; impedance matching network; metamaterials; ambient RF-Energy Harvesting; Wi-Fi bands

1. Introduction

RF-Energy Harvesting (RF-EH) systems have been a recurrent topic for the last decade [1–6]. The possibility of wireless feeding field sensors [7,8], RF-ID tags, or IoTs devices is closer every day [9–11], not only due to the tendency to reduce the power of each computational operation [10], but also due to the proliferation of the wasted ambient RF energy, produced by the continuous and growing wireless communication systems deployment [6,11–16]. Although there is a general consensus in the constituent functional blocks of a RF-EH system, different architectures and strategies have been proposed [3,4,12] including the possibility of combining the extraction of information and power from the same transmission [17,18]. However, from the point of view of the amount of collected energy, it is evident that a multiple frequency or broadband approach is the most convenient strategy, in order to take maximum advantage of the available ambient RF energy [14,19,20]. Examples of single [2], dual [14,21,22], multiple [12,13,15,23], and broadband frequency RF-EH systems [19,20] can be found in the literature. This work is framed in a basic stand-alone scheme, in which the energy is accumulated in a general-purpose storage element for further use. The Metamaterial Impedance Matching Network (MIMN) proposed in this work enhances the efficiency of a full ambient RF-EH system operating at 2.4 GHz and 5 GHz. Nevertheless, the technique could be extended to multiple bands by using metamaterial EBG transmission line structures controlling the electrical properties in multiple conduction bands. The rest of the functional blocks of the harvesting system are implemented using commercial-of-the-shell (COTS) elements. The antenna is a 2.5–5 GHz dual band from Molex [24], the rectification circuit is a full rectifier four-diode-bridge with SMS7630 Schottky diodes [25]; the Energy Management System (EMS) is a charge pump circuit based on the BQ25570 IC from Texas Instruments [26]. Finally, a 6.8 mF supercapacitor has been used as storage element due to its low losses and high speed response [27].
RF harvesting is based on the rectification and filtering of high frequency signals, which is inherently a highly non-linear process that challenges the impedance adaptation process. Several rectifier architectures such as the Garetz bridge [2,28–30], variations of the Dickson charge pump-rectifier circuits [31–33], or the Grenache rectifier [8–13], are commonly used in RFEH systems. In this design, the Garetz or bridge full wave rectifier has been chosen due to its simplicity and the fact that it is able to supply enough voltage to activate the input port of the BQ25570 nano power boost charger IC. Grenache and Dickson rectifiers introduce additional lumped capacitor that increases losses at the ultra-low power operation conditions. Communication classic impedance matching circuits are designed to guarantee the maximum power transfer at a single frequency, acting as a filter for the rest of the spectrum. The major power contribution in indoor environments is expected to be produced by the wireless domestic communication networks and specifically from Wi-Fi routers operating in the 2.4 GHz and 5 GHz bands [21,22].

The impedance matching has been one of the metamaterial applications since the popularization of the metamaterial concept introduction by J. Pendry [34] and D. Smith [35]. J. Mosig and C. Caloz, theoretically demonstrated the possibility of matching multiple bands using an extended composite right/left-handed transmission line [36]. An impedance matching EBG microstrip structure was proposed, fabricated, and tested in [37] using a composite right/left-handed transmission planar transmission line, including grounded vias. A dual band matching structure using Split Ring Resonators (SRR) was proposed in [38]. In this case, the utilization of SRR allows size reduction at the cost of degrading the quality factor and complicating the design process since there is not a clear relation between the physical dimensions of the microstrip structure and the SRR electrical parameters. Recently, other works point out the benefits of metasurfaces as impedance matching networks [5,39,40]. On the other hand, several optimization methods without any physical implementation, have been proposed to match the impedance using composite right/left-handed transmission lines in [41–43].

This work proposes the design, implementation, and test of a compact original microstrip MIMN structure, optimized using the ADS. Unlike other theoretical approaches or concept demonstrators, the proposed MIMN prototype performance is tested in a real and fully operative ambient RF-EH system.

Section 2 describes the proposed MIMN structure and the design process to match the impedance of the harvesting system. Section 4 is dedicated to describing the experimental setup and Section 5 exposes and discusses the experimental data and the rectifier efficiency characterization.

2. MIMN Background and Design Process

Metamaterial transmission lines can be described by an equivalent circuit model containing a series capacitance (C) and a grounded inductance (L) [44]. The MIMN proposed in this work is formed by two symmetric stacks of \( \lambda/2 \) microstrip resonators, capacitively coupled. The lateral coupling between the stubs, implements the metamaterial series capacitance. The \( \lambda/2 \) resonators behave as parallel RLC resonators around the resonant frequency. However, it can be shown that for \( \omega < \omega_0 = 1/\sqrt{LC} \) the imaginary part of the stub impedance is positive. In this case, neglecting loses, the equivalent circuit is basically a grounded L [45] that implements the shunt inductance of the metamaterial equivalent circuit model.

Figure 1 shows the equivalent circuit model of the MIMN structure. It can be easily shown that the characteristic impedance of the metamaterial transmission line is ruled by Equation (1).

\[
Z_0 = \sqrt{\frac{L}{C}} \tag{1}
\]
Figure 1. Equivalent circuit model of the proposed structure around the $\lambda/2$ stubs resonances of the capacitively coupled microstrips with a schematic of the MIMN around the microstrip stub resonant frequencies.

Unlike conventional transmission lines, $L$ and $C$ are independent variables in the metamaterials, which can be controlled by the stub length and width, and the inter-stub coupling distance. Due to the additional degrees of freedom, metamaterial transmission lines can be used to match the impedance in multiple frequencies.

The MIMN design process starts with the definition of the microstrip length ($l$) of the stubs to obtain the two first $\lambda/2$ resonances at 2.4 GHz and 4.8 GHz. The chosen substrate for the implementation is an Arlon 1000 with a dissipation factor of 0.003 and a high dielectric constant of $\varepsilon_r = 10$, obtaining a compromise between minimal size, structural robustness, and low losses at the operating frequencies. The substrate thickness is 1.27 mm (50 mils) with top and bottom 35 $\mu$m copper layers. The MIMN design is controlled by 4 parameters: the stubs length ($l$), the stubs width ($w$), the separation between adjacent stubs ($g$), and the gap between the input microstrip port and the stubs ($gp$). The central frequency of the operating bands is determined by the stub length that determines the $\lambda/2$ resonant frequency. Initial values for $L$ and $C$ can be analytically evaluated from the structure dimensions using classical well known expressions [46].

The design process finishes with the optimization of the MIMN loaded with the measured input impedance $Z_{Load}$ of the rectifier-EMC system. According to equation (2), the perfect match implies $S_{11} = 0$. The optimization process uses the length of the stubs ($l$) and the gap between microstrip ports ($gp$) as parameters to minimize $S_{11}$ around the two first stubs $\lambda/2$ resonant frequencies. In the process, the minimal width stubs and inter-stub gap have been fixed to 1 mm and 0.2 mm which are the minimal allowed fabrication distances.

$$S_{11} = \frac{Z_{Load} - Z_0}{Z_{Load} + Z_0}$$  \hspace{1cm} (2)

It has been experimentally verified that $S_{11}$ (and consequently $Z_{Load}$) of the bridge rectifier loaded with the EMS system, does not depend significantly on the input power in the range between 0 dBm and $-20$ dBm. Figure 2 shows the final dimensions resulting from the optimization process and a picture of the microstrip top layer of the fabricated MIMN structure.

The MIMN is a passive two port network that generates $S_{11}$ notches around the $\lambda/2$ open stubs resonators. These notches can be identified as resonant frequencies that minimize the $S_{11}$ parameter. The number of notches in the structure response is related to the number of coupled stubs. Two identical $\lambda/2$ open stubs capacitively coupled generate two split resonant frequencies around the original $\lambda/2$ resonance (see chapter 8 of [47]). In general $N$ stubs will generate $N-1$ notches; however, the quality factor of the new resonant frequencies decreases with $N$. The distance between the split frequencies depends on the coupling coefficient between the resonators which, in our case is basically controlled by the distance between adjacent stubs. Therefore, this coupling distance in an optimization
process can situate a deep notch at the desired frequency (2.4 GHz in our case). The MIMN takes advantage of these notches behavior to match the input impedance of the EMS in multiple frequencies simultaneously.

![Figure 2](image1.png) (a) Layout of the MIMN microstrip top layer with the physical dimensions: length $l = 22.8$ mm, coupled stubs width $w = 6.69$ mm, inter coupled stubs gap $g = 0.2$ mm, and gaps to the input and output ports $g_p = 0.4$ mm. (b) Image of the fabricated prototype.

The matched system has been simulated using ADS-Momentum co-simulation, combining the MIMN Momentum electro-magnetic model with the circuit bridge schematic. The SMS7630 model is generated by introducing the information supplied in the diode datasheet [25]. Figure 3 shows a reasonable agreement between the simulated and measured $S_{11}$ parameters. Several notches are observed in both simulated and measured $S_{11}$ curves, situated around the two first resonances of the $\lambda/2$ stubs. The number of notches is related to the number of unit cells in the metamaterial structure: 3 for the first resonance and 6 for the second (although some of them could be degenerated). $S_{11}$ reaches minimal values of $-36.54$ dB at 2.0 GHz and $-28.04$ dB at 5 GHz, indicating that the input and load impedance differ in 2.8%, and 3.9%, respectively. There is a notch in the measured response at 2.4 GHz with $S_{11} = -16.63$ dB indicating a difference of 28% between the impedances. Consequently, it can be said that the MIMN is matched in these notches.

![Figure 3](image2.png) (a) Measured and simulated $S_{11}$ parameter of the MIMN connected with the bridge rectifier $Z_L$ for $Pin = -15$ dB. (b) Scheme of the measurement setup.
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Figure 4 shows the measured impedance correction introduced by the MIMN in the bridge input impedance at the three main notch frequencies. MIMN effect can be interpreted as the result of a network with grounded inductance and shunt capacitance, which is coherent with the equivalent circuit model described in Figure 1. On the other hand, Figure 4 points out the multi-frequency impedance matching feature of the MIMN, obtaining a reasonable matching for three different frequencies with a single network.

![Figure 4. Measured effect of the MIMN in the bridge input impedance represented in the 50 $\Omega$ normalized Smith Chart, for 2.0 GHz, 2.4 GHz, and 5.0 GHz.](image)

3. Experimental Setup to Evaluate the MIMN

The effectivity of the MIMN has been evaluated by comparing its effect in a full operational RF-EH system performance. Except for the proposed MIMN, the RF-EH constituent blocks have been implemented using COTS elements. Figure 5 shows the components used in the implementation of the different RF-EH functional blocks.

RF-EH prototype measurements have been performed in normal ambient laboratory conditions. The nearest Wi-Fi source was a router outside the room, 5 m away from the testing point.
Figure 5. Components used to implement the different functional blocks of the RF-EH prototype. From left to right: Planar Wi-Fi antenna Combo 47950-0001 by Molex [24]; proposed MIMN; full wave bridge rectifier using SMS7630-061 Schottky diodes [25], included in the Harvest-1 PCB; EMS based on the BQ25570 nano power boost charger and bust converter by Texas Instruments [26]; 6.8 mF supercapacitor AVX BestCap ultra-low ESR [27].

Figure 6 shows the ambient power level captured by the planar Molex Combo antenna during a period of 5 min using the max-hold mode in the spectrum analyzer. After that period no further changes are observed in the measured spectrum. This measurement is used as the maxim RF power available in the ambient for the effective efficiency evaluation. The rectifier circuit is loaded with a 6.8 mF supercapacitor [27], zero bias Schottky diode [25] in a bridge rectifier. The 6.8 mF supercapacitor feeds an in-home developed EMS based on the BQ25570 IC [26]. Temporal variability of RF signals generates an unpredictable input power dynamic, hindering the determination of optimal input power conditions [2]. The BQ25570 IC implements a programmable maximum power point tracking (MPPT) sampling network, that optimizes and periodically updates the input power conditions. Thanks to this MPPT, the EMS is able to efficiently collect µW at the input ports and deliver mW pulses to the output storage element. The MPPT system checks the voltage in the EMS input every 16 s, recalculating the optimum input operating point for 256 ms, to resume the charge pumping in updated optimal conditions.

Figure 6. Measure of the maximum RF ambient power delivered by the 47950-0001 Molex Combo antenna. The measurement has been done with a Rohde Schwartz FSL6 spectrum analyzer with a frequential using the max-hold mode.
A 6.8 mF AVX BestCap Ultra-low ESR high power pulse supercapacitor [27] has been used as the storage element. This supercapacitor minimizes internal losses offering a fast response, suitable for powering RF-systems. The EMS PCB (Harvest-1) includes the bridge rectifier. The EMS offers three different outputs with maxim voltages ranging from 1.8 V to 4.2 V. For convenience, the 1.8 V output ($V_{\text{OUT}}$) has been chosen to evaluate the MIMN effect in the RF-EH performance.

Figure 7a,b show the schemes of the experimental setups with and without the MIMN. Figure 7c corresponds to an image of the implemented RF-EH system. The EMS is a self-powered system which operates in two different modes: the cold state (characterized by $V_{\text{OUT}} < 1.6$ V), and the efficient state (characterized by $V_{\text{OUT}} > 1.6$ V). In the cold state, the collected charge is used to setup the EMS self-polarizing IC voltages. A minimum of 330 mV, and current pulses with amplitudes large enough to generate µW power are required in the EMS input port. Above this threshold, the EMS starts to accumulate charge in the self-polarization capacitors. When $V_{\text{OUT}}$ reaches 1.6 V the EMS switches to a highly efficient mode in which the input minimal voltage to operate is reduced to a value between 80 mV and 100 mV. Once the 1.8 V is reached at the output storage element, the EMS stabilizes the $V_{\text{OUT}}$ voltage producing oscillations around 1.8 V.

**Figure 7.** (a) Scheme of the RF-EH with not matching network (NM). (b) Scheme of the RF-EH system with matching network (MIMN). (c) Images of the experimental setup.
The function of the 6.8 mF supercapacitor connected to the rectifier output and the EMS input port, is to accumulate enough charge to supply µW power packages keeping the 330 mV needed in the cold state (or 80 mV in the high efficiency state) minimizing losses.

4. Experimental Results and Discussion

Some authors have proposed the elimination of the lumped LC impedance matching networks in low power RF-EH, arguing that losses introduced by the network in these conditions may be comparable with the matching benefits [47,48]. Since one of the metamaterial transmission line characteristics is the high losses, it has been found interesting to compare the RF-EH system performance with and without the proposed MIMN.

Results shown in Figures 8–10 for the EMS input and output voltage, indicate that the MIMN enhances the RF-EH performance despite the losses. Figure 8 shows the voltage evolution at the EMS input (V_{in}) with and without the MIMN. During the cold state, V_{in} rises from zero to values between 330 mV and 270 mV. In this state, the harvested energy is used to accumulate charge in the EMS self-polarizing capacitors. On each voltage oscillation 408 µC is pumped into the EMS. As it can be observed in Figure 8, the charge pumping frequency is 50% faster when using MIMN.

![Figure 8. EMS Input voltage transient with (MIMN RF-EH) and without (NM RF-EH) proposed Metamaterial Impedance Matching Network (MIMN).](image)

The system formed by the antenna, the full wave rectifier, and the capacitor is a RF-DC transductor where the DC voltage is basically generated by the charge stored in 6.8 mF supercapacitor. This high speed and low loss storage element bias the EMS input and supplies the charge pumped into the battery by the EMS.

Figure 9 shows the switch between the cold state (characterized by oscillations between 330 mV and 270 mV) and the efficient state (characterized by a few mV oscillations around 80 mV), with (black line) and without (red line) using the MIMN.
Figure 9. EMS input voltage evolution at the EMS input ($V_{in}$ in Figure 7a) using MIMN (black line) and input ($V_{in}$ in Figure 7b) without matching network (red line).

Figure 10. EMS output voltage ($V_{out}$ in Figure 7) using a 6.8 mF supercapacitor as output storage element. The evolution between 0 and 1.6 V corresponds to the cold state. $V_{out}$ exhibits a linear behavior in the range $1.6 \, V < V_{out} < 1.8 \, V$.

The efficiency is the usual figure of merit used to characterize RF rectification process. It is strongly conditioned by the input impedance and the input power. Figure 10 shows the simulated efficiency of the bridge rectifier obtained through ADS harmonic balance analysis. SMS7630 datasheet information [25] has been included in the ADS Schottky diode model for simulations.

The available RF power in the ambient is in constant and unpredictable evolution. It depends on the WI-FI information transit but also on the number of active devices.
around and the proximity to the RF-EH system to the sources. It is reasonable to expect RF ambient power levels below $-30$ dBm (as it was shown in Figure 6). Figure 11 shows the efficiencies vs. input power for 2.4 and 5 GHz, using as $R_L$ the input impedance of the EMS ($R_L = 32\, \text{k}\Omega$).

![Figure 11. Simulated efficiencies of a SMS7630 diode bridge rectifier where $C_{\text{out}} = 6.8\, \text{mF}$. $R_L = 32\, \text{k}\Omega$ is the measured input impedance of the EMS. The analysis has been done using ADS harmonic balance simulation to estimate the ratio between RF input power ($P_{\text{in-RF}}$) and the DC output power delivered to the load ($P_{\text{output-DC}}$).](image)

As it can be seen in Figure 11, the expected efficiencies for a $-30$ dBm input power are below 15% at 2.4 GHz and below 2.5% at 5 GHz. Since there is available power in the 5.5 GHz band (see Figure 6), the efficiency has been also evaluated at this frequency; however, it is not expected a significant contribution to the RF-EH performance from this frequency. Similar efficiencies can be found in the literature [49–51] for RF low-power conditions (see Table 1).

<table>
<thead>
<tr>
<th>References</th>
<th>Frequency (GHz)</th>
<th>Input Power</th>
<th>Diode Type</th>
<th>$R_L$ (Ω)</th>
<th>RF-to-DC Efficiency (%)</th>
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<tr>
<td>[49]</td>
<td>2.4</td>
<td>$-10$ dBm</td>
<td>SMS7630</td>
<td>2.8 k</td>
<td>10</td>
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<tr>
<td>[50]</td>
<td>2.4</td>
<td>$-20$ dBm</td>
<td>SMS7630</td>
<td>5.3 k</td>
<td>18</td>
</tr>
<tr>
<td>[52]</td>
<td>2.45</td>
<td>$-30$ dBm</td>
<td>HSMS 2852</td>
<td>28 k</td>
<td>10</td>
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<tr>
<td>This Work</td>
<td>2.4</td>
<td>RF-Ambient ($&lt;-30$ dBm)</td>
<td>SMS7630</td>
<td>32 k</td>
<td>8.8</td>
</tr>
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</table>

Table 1. Summarizes some of the more recent efficiencies reported in the literature with similar systems to the proposed in this work.
The rectifier efficiency characterization shown in Figure 11 utilizes a monochromatic RF source to generate the input power ($P_{\text{in}}^{\text{DC}}$) and an output load ($R_L$) to evaluate the output power ($P_{\text{out}}^{\text{DC}}$). The effects of the load resistance in the efficiency can be observed in Figure 12. The maximum efficiency is observed for $R_L = 2.2 \, \text{k}\Omega$, while in the case $R_L = 32 \, \text{k}\Omega$ (the EMS input impedance) the efficiency is below 10%.

![Figure 12. Efficiencies of the bridge rectifier as a function of the load resistance at 2.4 GHz and 5 GHz (dash and continuous line, respectively) considering $P_{\text{input-RF}} = -30 \, \text{dBm}$. Measured estimated efficiency of the bridge rectifier with the MIMN using the RF ambient power as input source.](image)

The efficiency of the bridge rectifier with the MIMN is evaluated by simultaneously measuring the maxim ambient power in the 2.4 GHz Wi-FI band, and the output voltage for different $R_L$. Unfortunately, the matching notches observed in Figure 3 indicate that the 5.5 GHz band observed in Figure 6 does not contribute to the RF input power. The obtained measured efficiency estimation (dots plotted in Figure 12) shows the same behavior as the harmonic balance simulations at 2.4 and 5 GHz, indicating an 8.8% efficiency for $R_L = 32 \, \text{k}\Omega$ for the rectification of the RF ambient power.

The EMS extracts charge from the capacitor $C_{\text{out}}$ and pump it in a storage element (battery or supercapacitor) up to 1.8 V. The EMS requires 330 mV as minimum input voltage to operate in the cold state, and 80 mV in the efficiency state to operate as a charge pump. These values constitute the RF-EH threshold voltages that delimitate the sensibility of the EH system. Figure 13 shows the measured output voltage of the MIMN bridge rectifier system for different output loads and RF-ambient input power.

Figure 13 points out that the RF-EH matched with the MIMN is able to activate the charge pump of the EMS from the available RF ambient power. The efficiency is low, however, the possibility of matching multiple frequencies using the MIMN constitutes an interesting result to explore in further designs.
5. Conclusions

In this paper, a metamaterial impedance matching network (MIMN) has been designed, implemented, and tested, to match the impedance of an ambient RF-EH system. The metamaterial transmission line is based on coupled $\lambda/2$ microstrip resonators, being easy to control the central operating frequencies with the stubs dimensions. Three matched frequencies have been observed in the s-parameter measures of the matched RF-EH system: $S_{11} = -36.54\,\text{dB} @ 2.0\,\text{GHz}$, $S_{11} = -16.63\,\text{dB} @ 2.4\,\text{GHz}$, and $S_{11} = -28.04\,\text{dB} @ 5\,\text{GHz}$. The utilization of the MIMN enhances in a 50% the charging time of the RF-EH when the ambient power is below $-30\,\text{dBm}$. The efficiency of the matched rectifier has been experimentally estimated in 8.8% for $R_L = 32\,\text{k}\Omega$. The possibility of matching multiple frequencies simultaneously constitutes a promising result to be applied in further designs.

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